

					Sheet	1	of	1
Form PTO-1449 (REV. 8-83)		US Dept. of Commerce PATENT & TRADEMARK OFFICE		ATTY DOCKET NO. 118315		APPLICATION NO. New U.S. Patent Application		
INFORMATION DISCLOSURE STATEMENT								
(Use several sheets if necessary)				APPLICANTS Atsushi TAKAKUWA et al.				
				FILING DATE January 12, 2004				
U.S. PATENT DOCUMENTS								
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME		CLASS	SUB CLASS	
<i>MSL</i>	1	6,057,067	5/2/2000	ISBERG et al.				
FOREIGN PATENT DOCUMENTS								
		DOCUMENT NUMBER	DATE	COUNTRY		CLASS	SUB CLASS	
<i>MSL</i>	2	JP A 10-125929 w/ Abst & Trans	5/15/1998	Japan				
	3	JP A 10-125930 w/ Abst & Trans	5/15/1998	Japan				
	4	JP A 10-125931 w/ Abst & Trans	5/15/1998	Japan				
	5	JP A 11-26733 w/ Abst & Trans	1/29/1999	Japan				
	6	JP A 2000-133809 w/ Abst & Trans	5/12/2000	Japan				
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	11	JP A 2003-031778 w/ Abst & Trans	1/31/2003	Japan				
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OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)								
<i>MSL</i>	13	Tatsuya SHIMODA et al., "Surface Free Technology by Laser Annealing (SUFTLA)", 1999, IEEE, Pgs., IEDM 99-289-292						
	14	Sumio UTSUNOMIYA et al., "Low-temperature poly-Si TFT transferred onto plastic substrates by using surface free technology by laser ablation/annealing (SUFTLA <sup>®</sup> )", Journal of the SID, 2002, Pgs., 69-73						
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<i>MSL</i>	20	S. UTSUNOMIYA et al., "Flexible Color AM-OLED Display Fabricated Using Surface Free Technology by Laser Ablation/Annealing (SUFTLA <sup>®</sup> ), and Ink-jet Printing Technology", SID, 2003, Pgs., 864-867						
EXAMINER				<i>[Signature]</i>		DATE CONSIDERED		
						<i>1/22/04</i>		
Examiner: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.								

Date: January 12, 2004